

	Type	L #	Hits	Search Text	DBs
1	BFS	L1	319780	257/\$.ccis. 438/\$.ccis.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BFS	L2	9461	1 and (TFT or TFT-LCD or (thin near film near transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BFS	L3	60	2 and (fourth near photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BFS	L5	1223	kobayashi-kazuhiko or nakamura-hobunji or inoue-kazunori or yoshida-takuji or nakashima-ken or masutani-yuichi or aoki-hironori).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	BFS	L6	104	5 and (TFT or TFT-LCD or (thin near film near transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	BFS	L7	5	6 and (fourth near photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	BFS	L8	16779	(TFT or TFT-LCD or (thin near film near transistor)).ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
8	BFS	L9	45	8 and (fourth near photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
9	BFS	L10		9 and (fourth near near hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
10	BFS	L11	44838	(TFT or TFT-LCD or (thin near film near transistor)).	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
11	BFS	L12	91	11 and (fourth near photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
12	BFS	L13	40	12 and (contact near hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB